

SS22AD THRU SS210AD

Surface Mount Schottky Barrier Rectifier

Reverse Voltage - 20 to 100 V

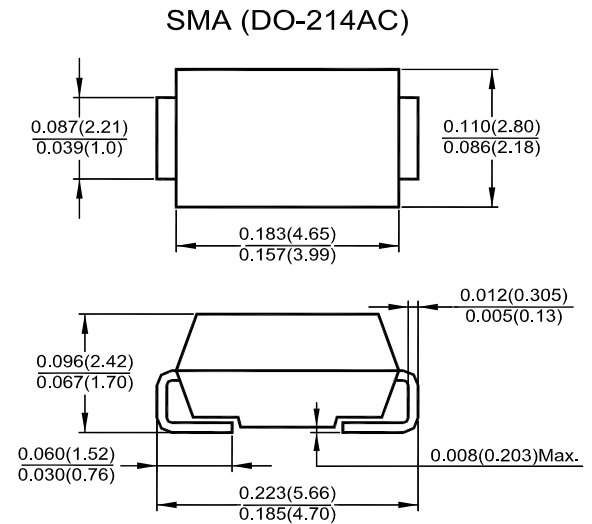
Forward Current - 2 A

Features

- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- The plastic package carries Underwriters Laboratory flammability Classification 94V-0
- High forward surge current capability
- Built-in strain relief, ideal for automated placement

Mechanical Data

- **Case:** SMA (DO-214AC) molded plastic body
- **Terminals:** Leads solderable per MIL-STD-750, Method 2026
- **Polarity:** Color band denotes cathode end
- **Mounting Position:** Any



Dimensions in inches and (millimeters)

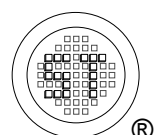
Maximum Ratings and Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave 60 Hz, resistive or inductive load, For capacitive load current derate by 20 %.

Parameter	Symbol	SS22AD	SS23AD	SS24AD	SS25AD	SS26AD	SS28AD	SS210AD	Unit
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	20	30	40	50	60	80	100	V
Maximum RMS Voltage	V _{RMS}	14	21	28	35	42	56	70	V
Maximum DC Blocking Voltage	V _{DC}	20	30	40	50	60	80	100	V
Maximum Average Forward Rectified Current	I _{F(AV)}	2							A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I _{FSM}	50							A
Maximum Instantaneous Forward Voltage at 2 A	V _F	0.55			0.75		0.85		V
Maximum DC Reverse Current at Rated DC Blocking Voltage T _a = 25 °C T _a = 100 °C	I _R	0.5							mA
		20			10				
Typical Junction Capacitance ¹⁾	C _j	220			180				pF
Typical Thermal Resistance ²⁾	R _{θJA}	75							°C/W
Operating Junction Temperature Range	T _j	- 65 to + 125			- 65 to + 150				°C
Storage Temperature Range	T _{stg}	- 65 to + 150							°C

¹⁾ Measured at 1MHz and applied reverse voltage of 4 V DC.

²⁾ P.C.B mounted with 0.2 X 0.2" (5 X 5 mm) copper pad areas.



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